

V_{DSS}	200V
$R_{DS(on)}$ (Max.)	325m Ω
I_D	7.5A
P_D	20W

●Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Drive circuits can be simple.
- 4) Parallel use is easy.
- 5) Pb-free lead plating ; RoHS compliant
- 6) 100% Avalanche tested

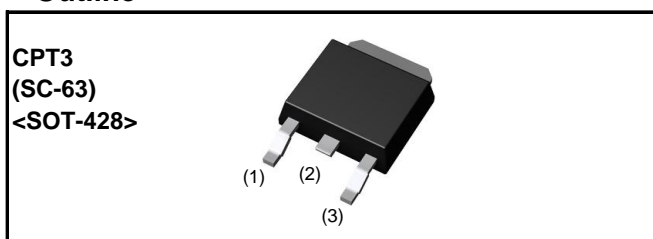
●Application

Switching Power Supply
 Automotive Motor Drive
 Automotive Solenoid Drive

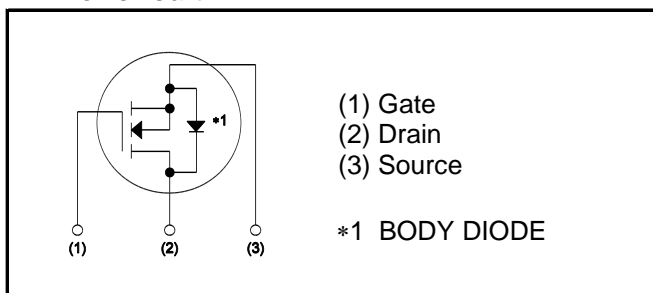
●Absolute maximum ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V_{DSS}	200	V
Continuous drain current	$T_c = 25^\circ\text{C}$	I_D^{*1}	± 7.5 A
	$T_c = 100^\circ\text{C}$	I_D^{*1}	± 4.1 A
Pulsed drain current	$I_{D,pulse}^{*2}$	± 30	A
Gate - Source voltage	V_{GSS}	± 30	V
Avalanche energy, single pulse	E_{AS}^{*3}	4.13	mJ
Avalanche current	I_{AS}^{*3}	3.75	A
Power dissipation	$T_c = 25^\circ\text{C}$	P_D	20 W
	$T_a = 25^\circ\text{C}^{*4}$	P_D	0.85 W
Junction temperature	T_j	150	$^\circ\text{C}$
Range of storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

●Outline



●Inner circuit



●Packaging specifications

Type	Packaging	Taping
	Reel size (mm)	330
	Tape width (mm)	16
	Basic ordering unit (pcs)	2,500
	Taping code	TL
	Marking	C07N20

●Thermal resistance

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
Thermal resistance, junction - case	R_{thJC}	-	-	6.25	°C/W
Thermal resistance, junction - ambient ^{*4}	R_{thJA}	-	-	147	°C/W
Soldering temperature, wavesoldering for 10s	T_{sold}	-	-	265	°C

●Electrical characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 1mA$	200	-	-	V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 200V, V_{GS} = 0V$ $T_j = 25^\circ\text{C}$	-	-	10	μA
		$V_{DS} = 200V, V_{GS} = 0V$ $T_j = 125^\circ\text{C}$	-	-	100	
Gate - Source leakage current	I_{GSS}	$V_{GS} = \pm 30V, V_{DS} = 0V$	-	-	± 100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = 10V, I_D = 1mA$	3.25	-	5.25	V
Static drain - source on - state resistance	$R_{DS(on)}$ ^{*5}	$V_{GS} = 10V, I_D = 3.75A$	-	250	325	$m\Omega$
		$V_{GS} = 10V, I_D = 3.75A$ $T_j = 125^\circ\text{C}$	-	515	670	
Forward transfer admittance	g_{fs}	$V_{DS} = 10V, I_D = 3.75A$	1.5	3.0	-	S

●Electrical characteristics (T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Input capacitance	C _{iss}	V _{GS} = 0V	-	755	-	pF
Output capacitance	C _{oss}	V _{DS} = 25V	-	55	-	
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	25	-	
Turn - on delay time	t _{d(on)} ^{*5}	V _{DD} ≈ 100V, V _{GS} = 10V	-	20	-	ns
Rise time	t _r ^{*5}	I _D = 3.75A	-	22	-	
Turn - off delay time	t _{d(off)} ^{*5}	R _L = 26.67Ω	-	24	-	
Fall time	t _f ^{*5}	R _G = 10Ω	-	12	-	

●Gate Charge characteristics (T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Total gate charge	Q _g ^{*5}	V _{DD} ≈ 100V	-	15	-	nC
Gate - Source charge	Q _{gs} ^{*5}	I _D = 7.5A	-	6	-	
Gate - Drain charge	Q _{gd} ^{*5}	V _{GS} = 10V	-	6	-	
Gate plateau voltage	V _(plateau)	V _{DD} ≈ 100V, I _D = 7.5A	-	7.4	-	V

●Body diode electrical characteristics (Source-Drain)(T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Continuous source current	I _S ^{*1}	T _c = 25°C	-	-	7.5	A
Pulsed source current	I _{SM} ^{*2}		-	-	30	A
Forward voltage	V _{SD} ^{*5}	V _{GS} = 0V, I _S = 7.5A	-	-	1.5	V
Reverse recovery time	t _{rr} ^{*5}	I _S = 3.75A	-	75	-	ns
Reverse recovery charge	Q _{rr} ^{*5}	di/dt = 100A/μs	-	220	-	nC

*1 Limited only by maximum temperature allowed.

*2 P_w ≤ 10μs, Duty cycle ≤ 1%

*3 L ≈ 500μH, V_{DD} = 50V, R_G = 25Ω, starting T_j = 25°C

*4 Mounted on a epoxy PCB FR4 (20mm × 20mm × 0.8mm)

*5 Pulsed

●Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

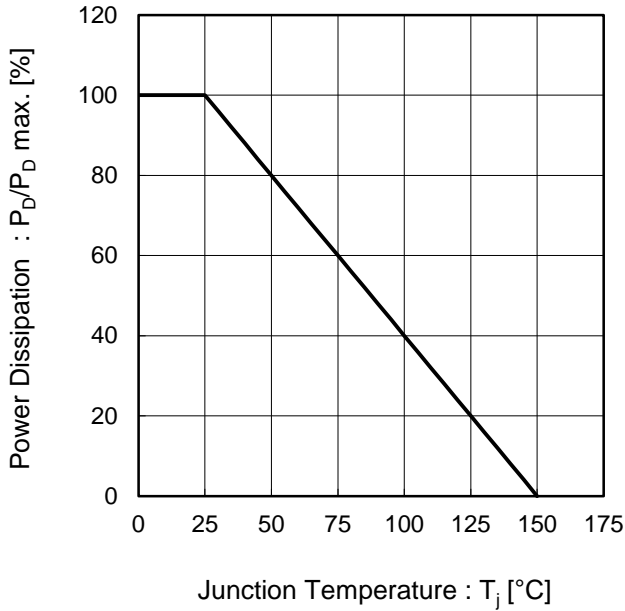


Fig.2 Maximum Safe Operating Area

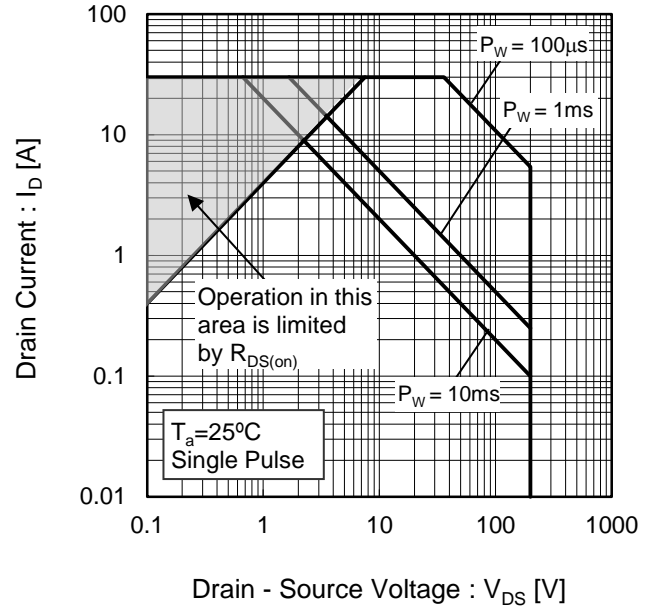
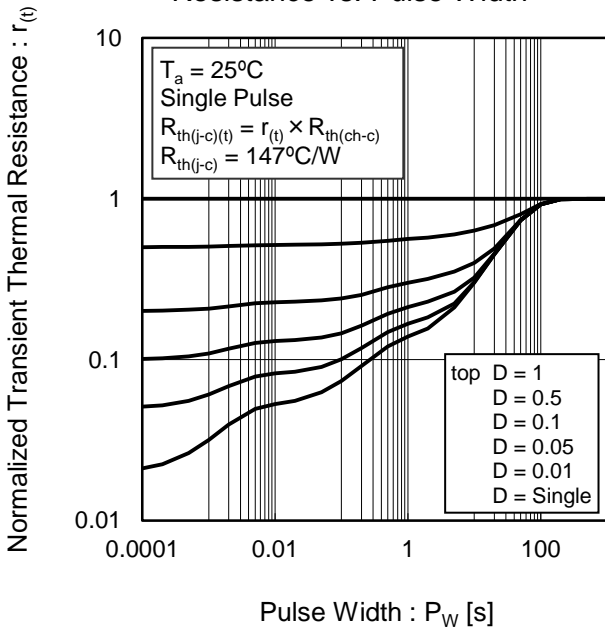


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width



●Electrical characteristic curves

Fig.4 Avalanche Current vs Inductive Load

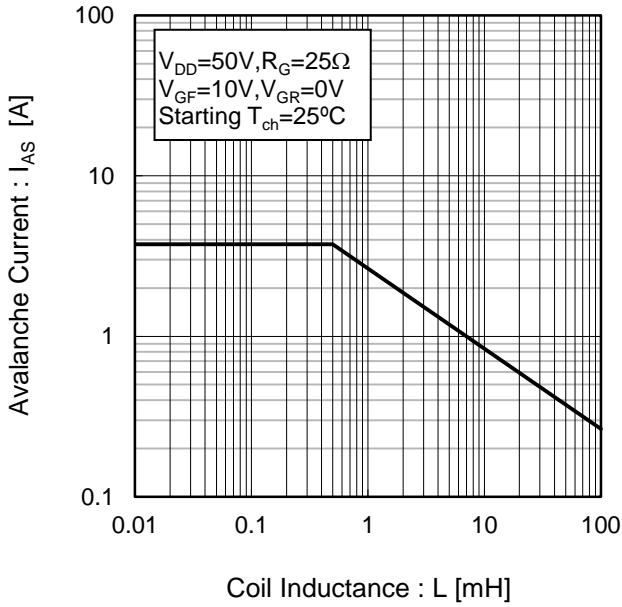


Fig.5 Avalanche Energy Derating Curve vs Junction Temperature

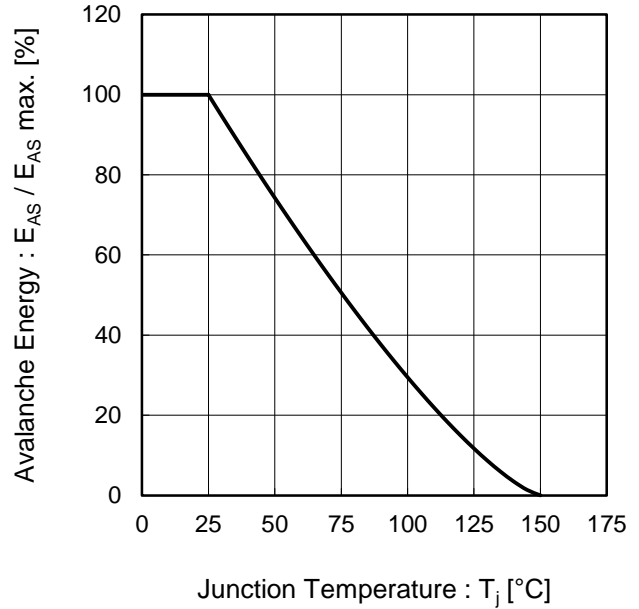


Fig.6 Typical Output Characteristics(I)

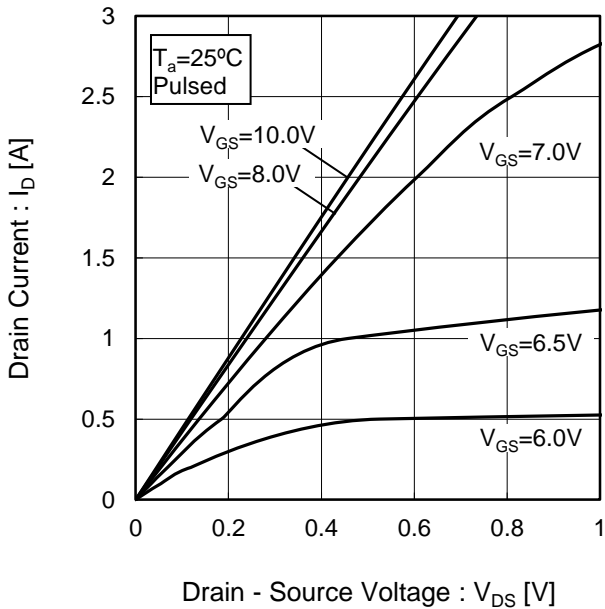
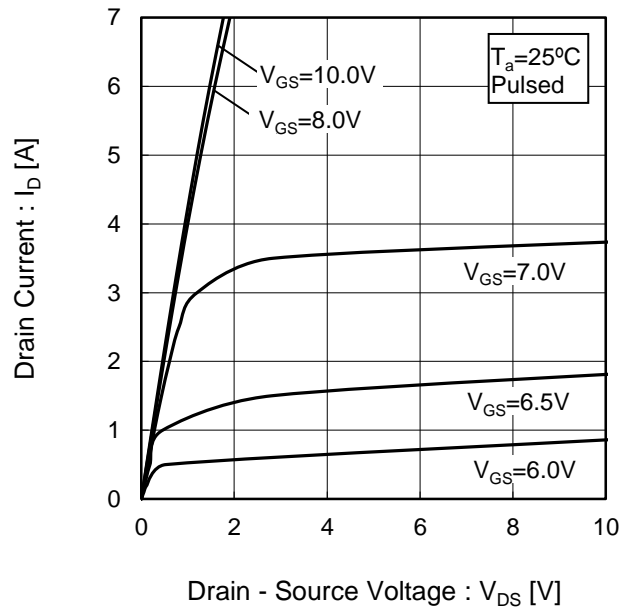


Fig.7 Typical Output Characteristics(II)



●Electrical characteristic curves

Fig.8 Breakdown Voltage vs. Junction Temperature

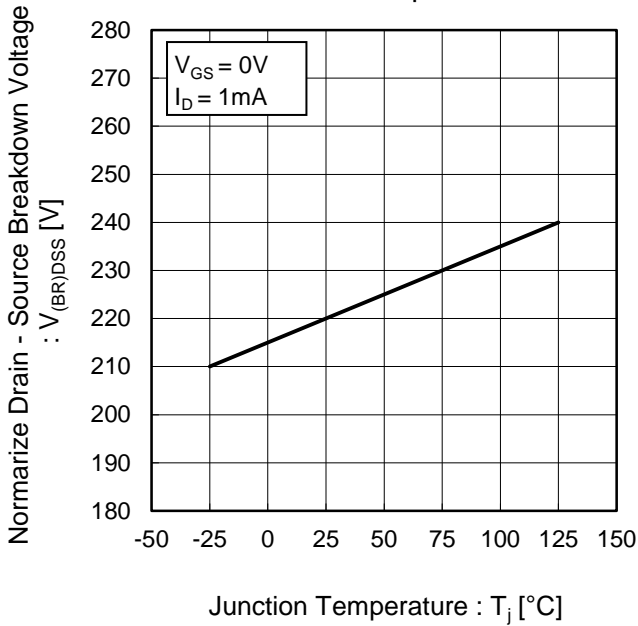


Fig.9 Typical Transfer Characteristics

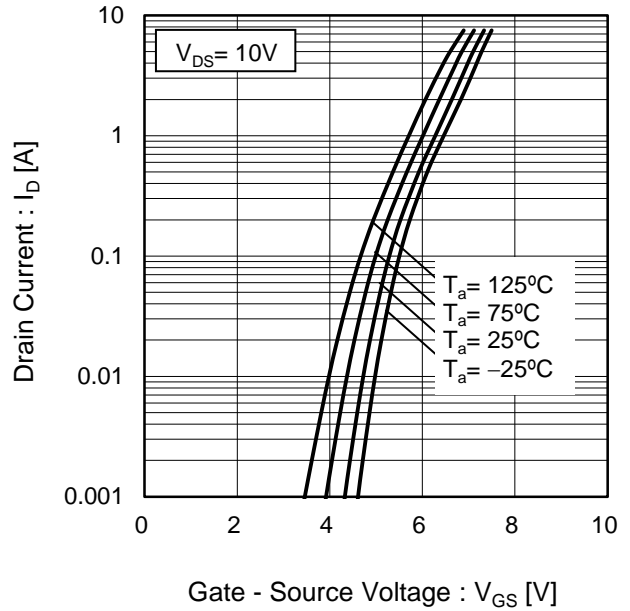


Fig.10 Gate Threshold Voltage vs. Junction Temperature

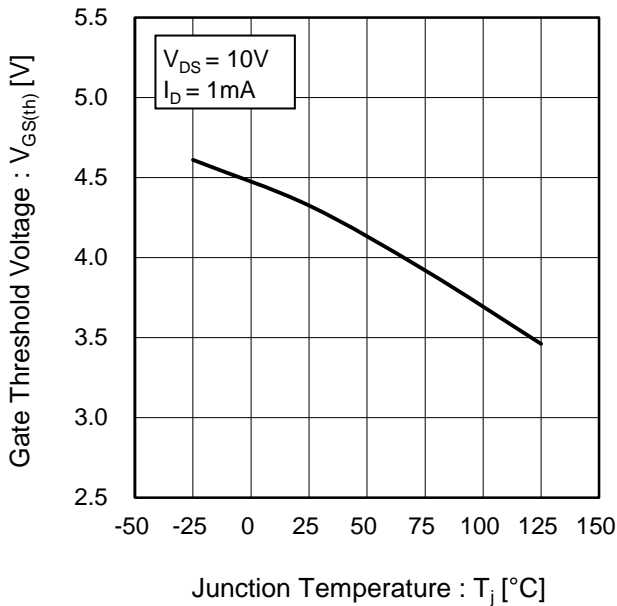
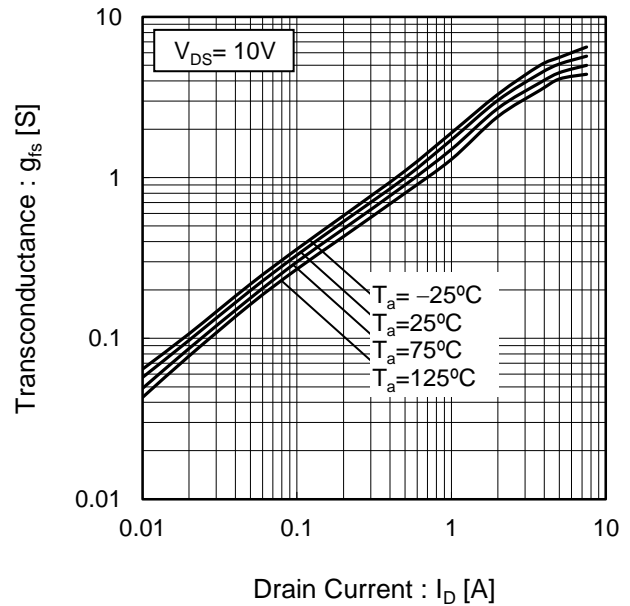


Fig.11 Transconductance vs. Drain Current



●Electrical characteristic curves

Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

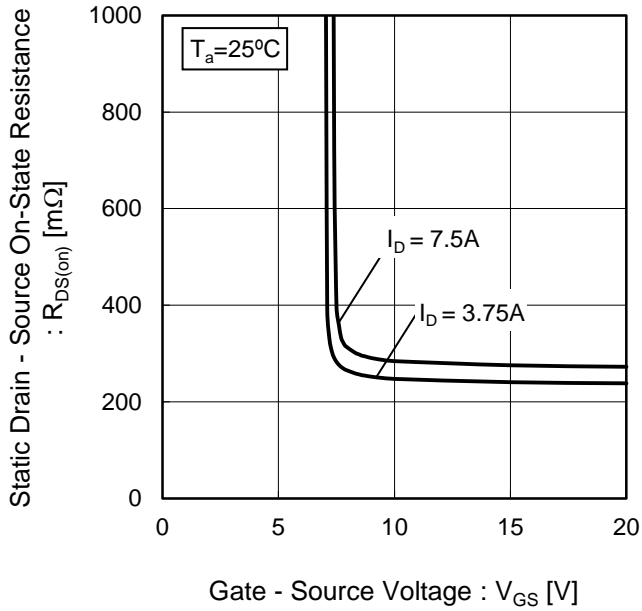


Fig.13 Static Drain - Source On - State Resistance vs. Drain Current(I)

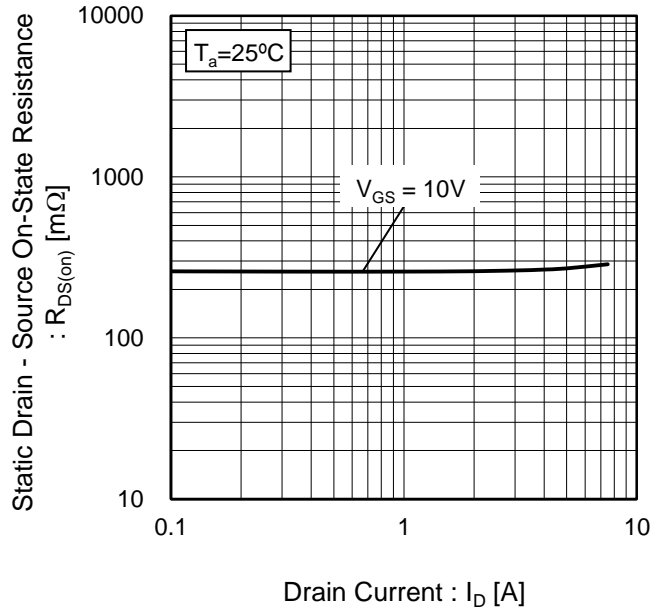
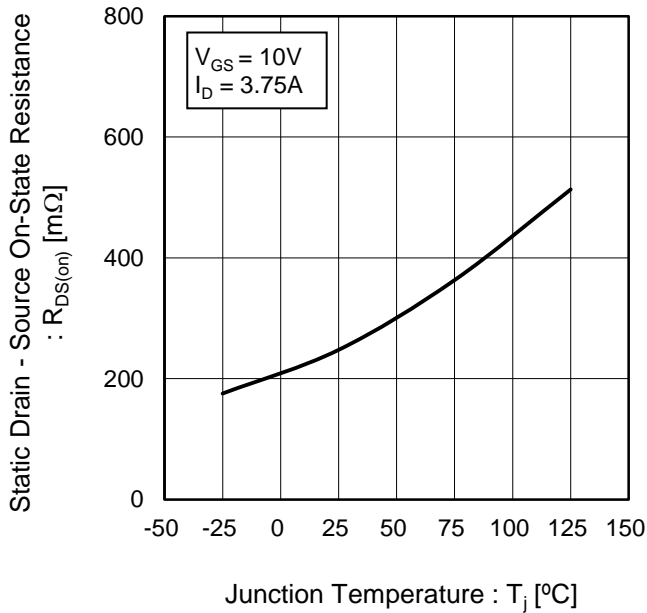


Fig.14 Static Drain - Source On - State Resistance vs. Junction Temperature



●Electrical characteristic curves

Fig.15 Static Drain - Source On - State Resistance vs. Drain Current(I)

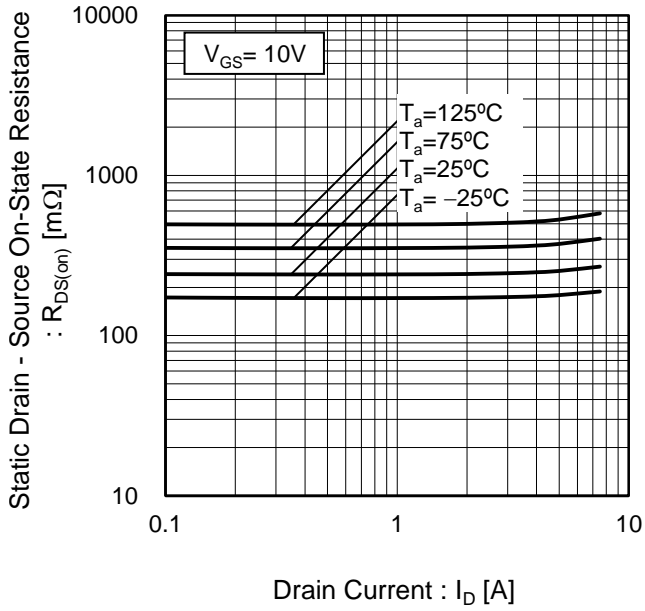
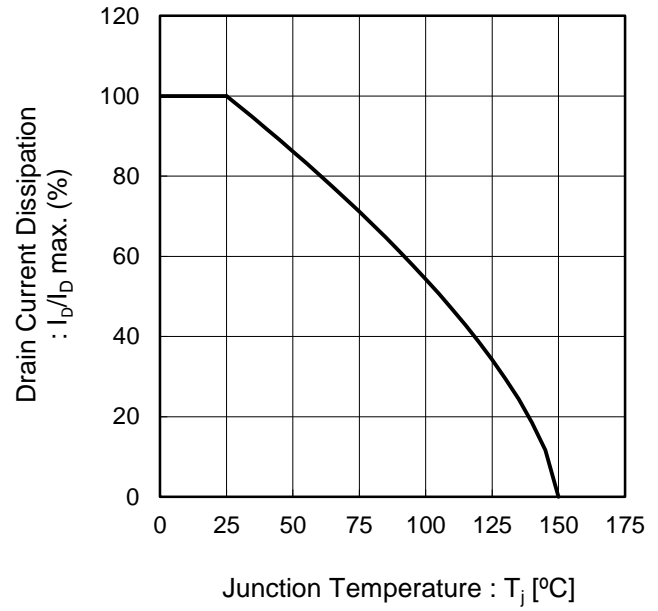


Fig.16 Drain Current Derating Curve



●Electrical characteristic curves

Fig.17 Typical Capacitance vs. Drain - Source Voltage

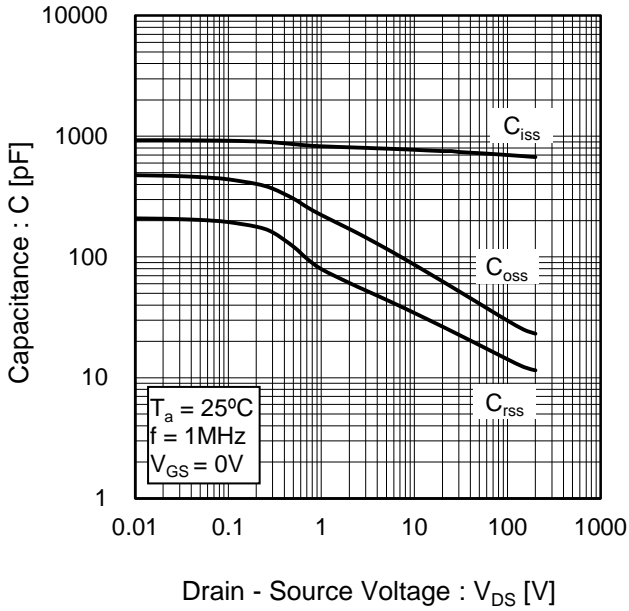


Fig.18 Switching Characteristics

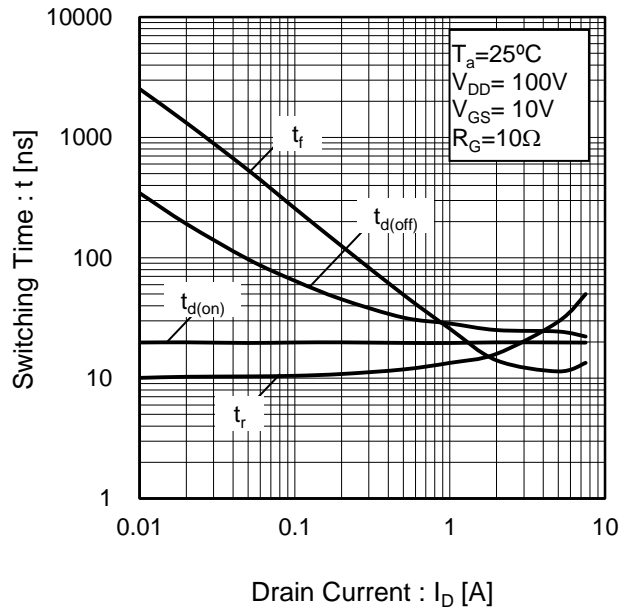
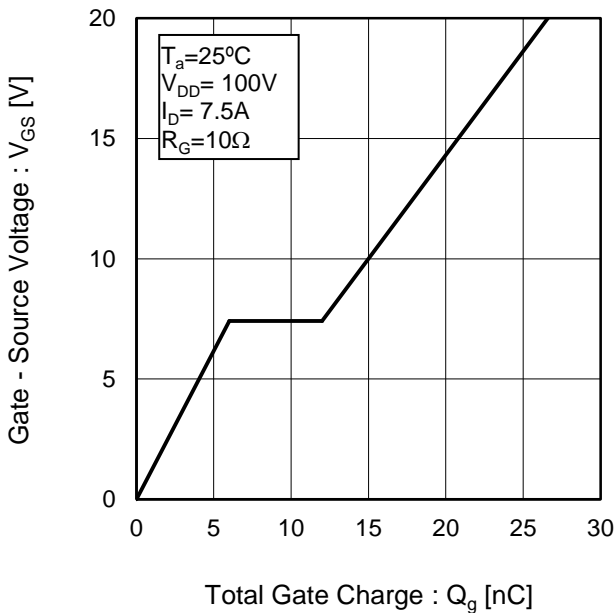


Fig.19 Dynamic Input Characteristics



●Electrical characteristic curves

Fig.20 Source Current vs. Source - Drain Voltage

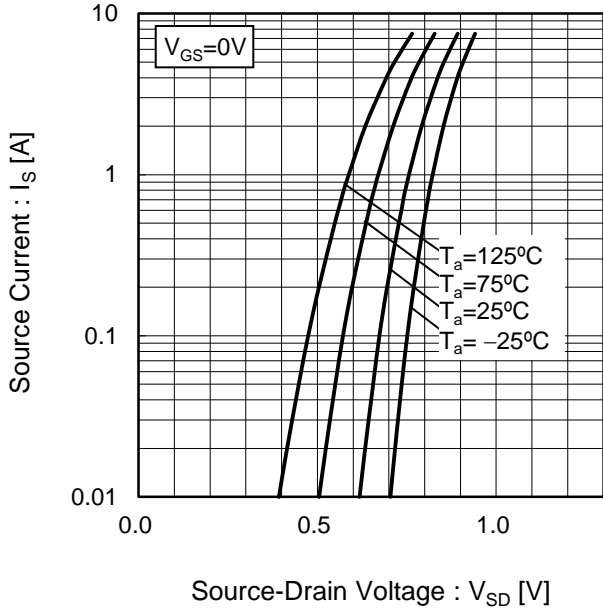
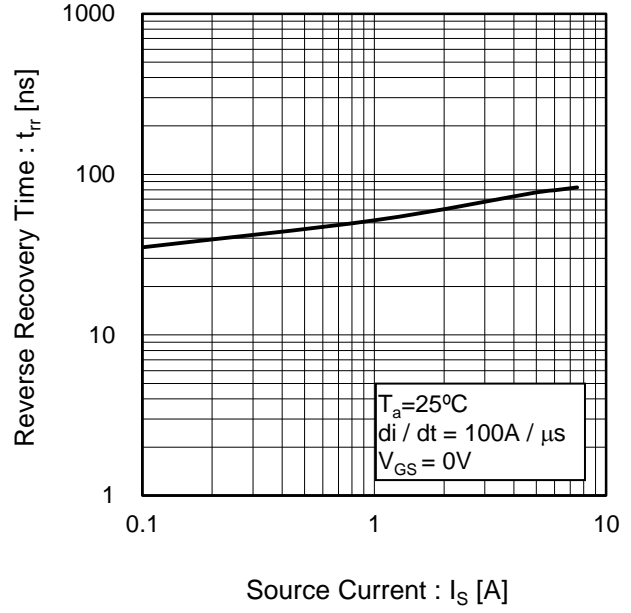


Fig.21 Reverse Recovery Time vs. Source Current



●Measurement circuits

Fig.1-1 Switching Time Measurement Circuit



Fig.1-2 Switching Waveforms

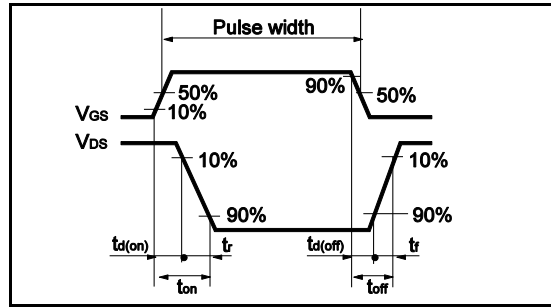


Fig.2-1 Gate Charge Measurement Circuit



Fig.2-2 Gate Charge Waveform

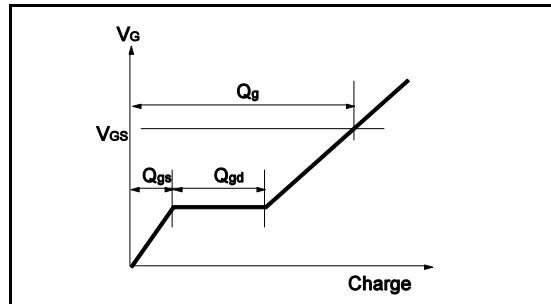


Fig.3-1 Avalanche Measurement Circuit

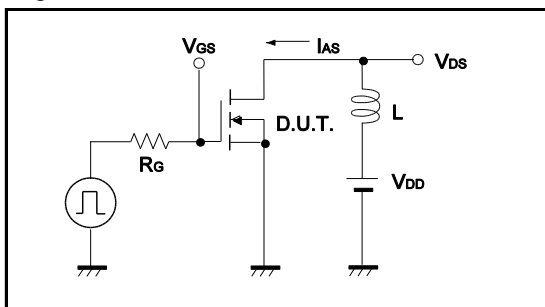
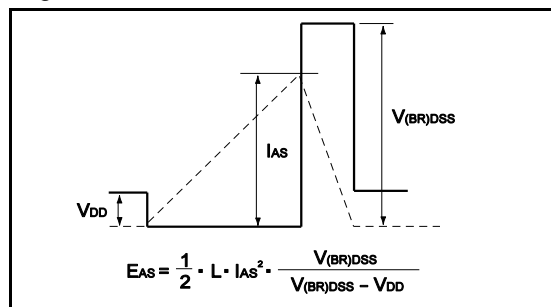
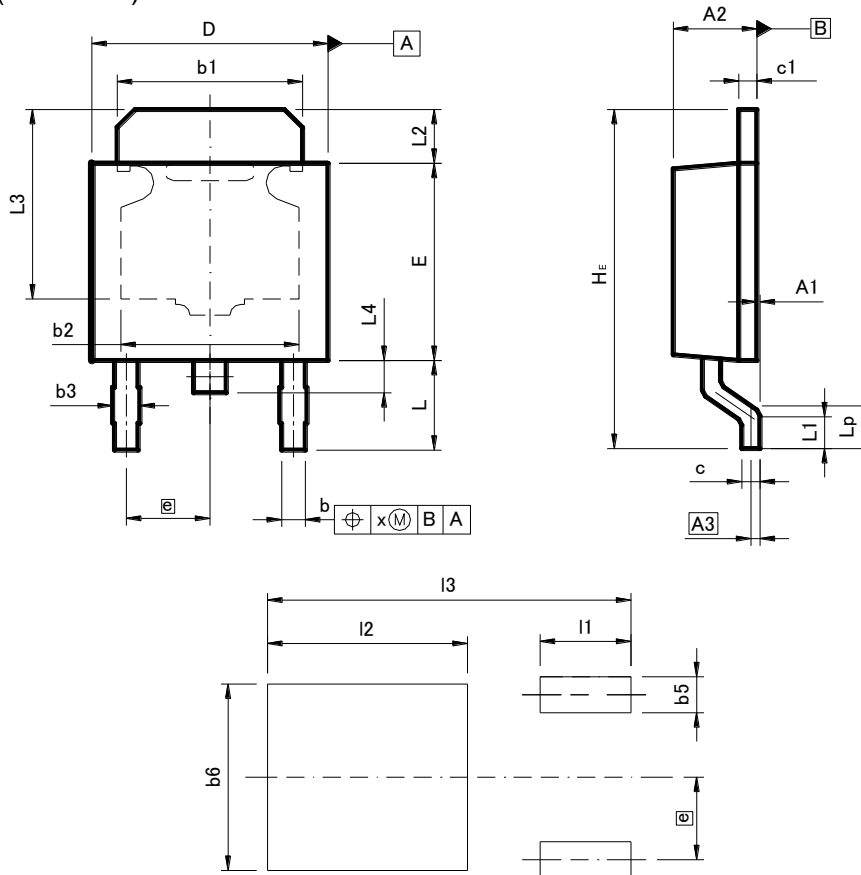


Fig.3-2 Avalanche Waveform



●Dimensions (Unit : mm)

CPT3



DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A1	0.00	0.15	0	0.006
A2	2.20	2.50	0.087	0.098
A3	0.25		0.01	
b	0.55	0.75	0.022	0.03
b1	5.00	5.30	0.197	0.209
b2	5.00		0.20	
b3	0.75		0.03	
c	0.40	0.60	0.016	0.024
c1	0.40	0.60	0.016	0.024
D	6.30	6.70	0.248	0.264
E	5.40	5.80	0.213	0.228
e	2.30		0.09	
HE	9.00	10.00	0.354	0.394
L	2.20	2.80	0.087	0.11
L1	0.80	1.40	0.031	0.055
L2	1.20	1.80	0.047	0.071
L3	5.30		0.209	
L4	0.90		0.035	
Lp	1.00	1.60	0.039	0.063
x	-	0.25	-	0.01

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b5	-	1.00	-	0.04
b6	-	5.20	-	0.205
I1	-	2.50	-	0.098
I2	-	5.50	-	0.217
I3	-	10.00	-	0.394

Dimension in mm/inches

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